# **HEF4585B**

# 4-bit magnitude comparator Rev. 6 — 21 November 2011

Product data sheet

#### **General description** 1.

The HEF4585B is a 4-bit magnitude comparator that compares two 4-bit words, A and B, and determines whether A is greater than B, A is equal to B, or A is less than B. Each word has four parallel inputs (A0 to A3 and B0 to B3) with A3 and B3 being the most significant inputs. Three outputs are provided: A greater than B (QA>B), A less than B (QA<B) and A equal to B (QA=B). Three expander inputs (IA>B, IA<B, and IA=B) allow cascading of the devices, to compare 8, 12, 16, ..., bits without external gates.

To operate a single device or a device in the least significant position in a cascaded chain, the expander inputs are connected as follows: IA=B = IA>B = HIGH and IA<B = LOW. All other cascaded devices have IA=B and IA<B connected to QA=B and QA<B respectively of the previous (less significant) device in the chain, while input IA>B is connected to a HIGH (see Figure 6). Operation is not restricted to pure binary code; the devices will work with any monotonic code. Table 3 describes the operation of the device under all possible logic conditions.

It operates over a recommended V<sub>DD</sub> power supply range of 3 V to 15 V referenced to V<sub>SS</sub> (usually ground). Unused inputs must be connected to V<sub>DD</sub>, V<sub>SS</sub>, or another input.

#### **Features and benefits** 2.

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

#### **Ordering information** 3.

Table 1. **Ordering information** All types operate from -40 °C to +85 °C

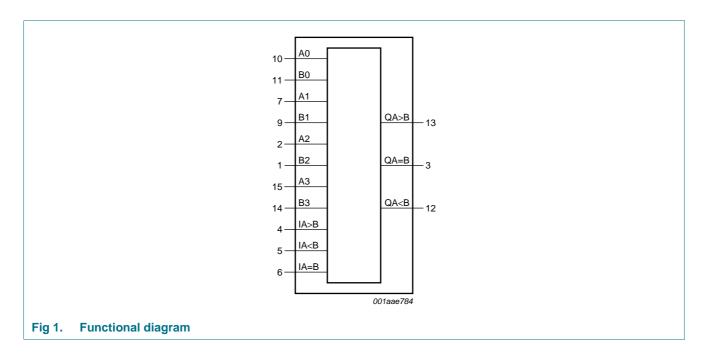
Type number	Package	Package							
	Name	Description	Version						
HEF4585BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4						
HEF4585BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1						

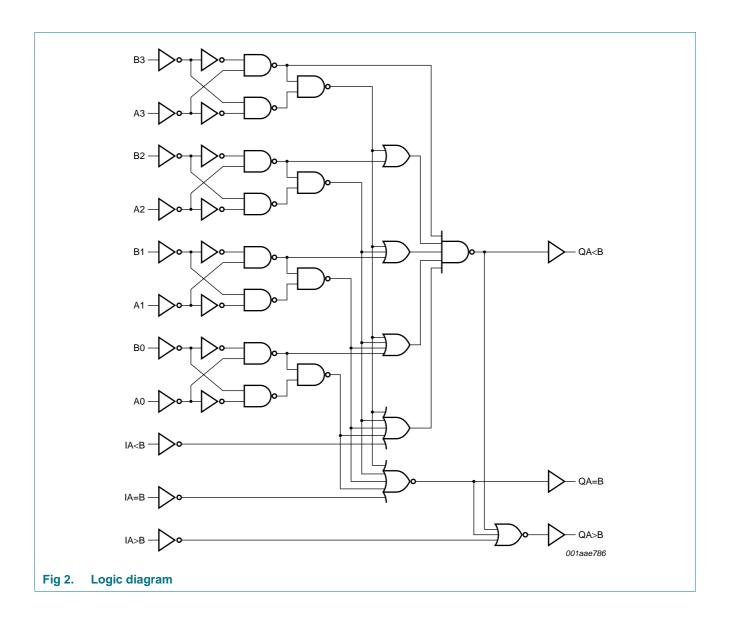


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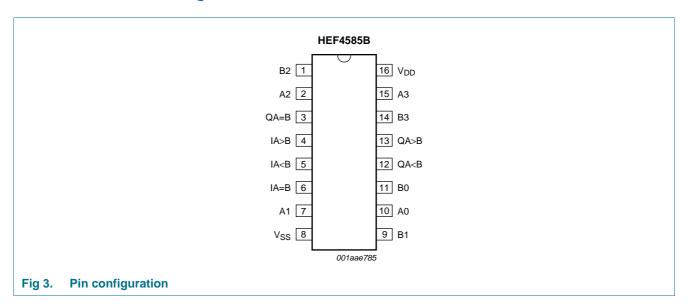
## 4. Functional diagram





## 5. Pinning information

#### 5.1 Pinning



## 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
A[0:3]	10, 7, 2, 15	word A parallel input
B[0:3]	11, 9, 1, 14	word B parallel input
IA>B	4	expander input
IA=B	6	expander input
IA <b< td=""><td>5</td><td>expander input</td></b<>	5	expander input
QA>B	13	A greater than B output
QA=B	3	A equal to B output
QA <b< td=""><td>12</td><td>A less than B output</td></b<>	12	A less than B output
$V_{DD}$	16	supply voltage
V <sub>SS</sub>	8	ground supply voltage

## 6. Functional description

Table 3. Function selection [1]

Comparin	g inputs			Cascadi	ng inputs		Outputs	Outputs		
A3, B3	A2, B2	A1, B1	A0, B0	IA>B	IA <b< td=""><td>IA=B</td><td>QA&gt;B</td><td>QA<b< td=""><td>QA=B</td></b<></td></b<>	IA=B	QA>B	QA <b< td=""><td>QA=B</td></b<>	QA=B	
A3 > B3	Χ	Χ	X	Н	Χ	Χ	Н	L	L	
A3 < B3	Χ	Χ	Χ	Χ	Χ	Χ	L	Н	L	
A3 = B3 A	A2 > B2	Χ	Χ	Н	Χ	Χ	Н	L	L	
	A2 < B2	Χ	Χ	Χ	Χ	Χ	L	Н	L	
	A2 = B2	A1 > B1	Χ	Н	Χ	Χ	Н	L	L	
			A1 < B1	Χ	Χ	Χ	Χ	L	Н	L
		A1 = B1	A0 > B0	Н	Χ	Χ	Н	L	L	
			A0 < B0 A0 = B0	Χ	Χ	Χ	L	Н	L	
				Χ	L	Н	L	L	Н	
				Н	L	L	Н	L	L	
				X	Н	L	L	Н	L	
				[2]						
			X	Н	Н	L	Н	Н		
				L	L	L	L	L	L	

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care.

## 7. Limiting values

**Table 4.** Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+18	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-	±10	mA
V <sub>I</sub>	input voltage		-0.5	$V_{DD} + 0.5$	V
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I <sub>I/O</sub>	input/output current		-	±10	mA
T <sub>stg</sub>	storage temperature		<del>-</del> 65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C
P <sub>tot</sub>	total power dissipation	DIP16 package	<u>[1]</u> _	750	mW
		SO16 package	[2] _	500	mW
Р	power dissipation	per output	-	100	mW

<sup>[1]</sup> For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

<sup>[2]</sup> The first 11 lines describe the normal operation under all conditions that will occur in a single device or in a serial expansion scheme. The last 2 lines describe the operation under abnormal conditions on the cascading inputs. These conditions occur when the parallel expansion technique is used.

<sup>[2]</sup> For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DD}$	supply voltage		3	-	15	V
VI	input voltage		0	-	$V_{DD}$	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	-	0.08	μs/V

## 9. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$  V;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	T <sub>amb</sub> =	–40 °C	T <sub>amb</sub> =	25 °C	T <sub>amb</sub> = 85 °C		Unit
				Min	Max	Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	$ I_{O}  < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
$V_{IL}$	LOW-level input voltage	$ I_{O}  < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V <sub>OH</sub>	HIGH-level output voltage	$ I_{O}  < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V <sub>OL</sub> LOW	LOW-level output voltage	$ I_{O}  < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I <sub>OH</sub>	HIGH-level output current	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	mΑ
		$V_0 = 4.6 \text{ V}$	5 V	-	-0.52	-	-0.44	-	-0.36	mΑ
		$V_{O} = 9.5 V$	10 V	-	-1.3	-	-1.1	-	-0.9	mΑ
		$V_0 = 13.5 \text{ V}$	15 V	-	-3.6	-	-3.0	-	-2.4	mΑ
I <sub>OL</sub>	LOW-level output current	$V_0 = 0.4 \ V$	5 V	0.52	-	0.44	-	0.36	-	mΑ
		$V_0 = 0.5 \ V$	10 V	1.3	-	1.1	-	0.9	-	mΑ
		$V_0 = 1.5 \text{ V}$	15 V	3.6	-	3.0	-	2.4	-	mΑ
I	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
$I_{DD}$	supply current	$I_O = 0 A$	5 V	-	20	-	20	-	150	μΑ
			10 V	-	40	-	40	-	300	μΑ
			15 V	-	80	-	80	-	600	μΑ
Cı	input capacitance		-	-	-	-	7.5	-	-	pF

## 10. Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS} = 0 \text{ V}$ ;  $T_{amb} = 25 \text{ °C}$ ; for test circuit see <u>Figure 5</u> unless otherwise specified.

Symbol	Parameter	Conditions[1][2]	$V_{DD}$	Extrapolation formula[3]	Min	Тур	Max	Unit
$t_{PHL}$	HIGH to LOW	An, Bn to Qn;	5 V	133 ns + (0.55 ns/pF)C <sub>L</sub>	-	160	320	ns
	propagation delay	see <u>Figure 4</u>	10 V	54 ns + (0.23 ns/pF)C <sub>L</sub>	-	65	130	ns
			15 V	37 ns + (0.16 ns/pF)C <sub>L</sub>	-	45	90	ns
	In to Qn;	5 V	83 ns + (0.55 ns/pF)C <sub>L</sub>	-	110	220	ns	
	see <u>Figure 4</u>	10 V	34 ns + (0.23 ns/pF)C <sub>L</sub>	-	45	90	ns	
			15 V	22 ns + (0.16 ns/pF)C <sub>L</sub>	-	30	60	ns
t <sub>PLH</sub>	LH LOW to HIGH	An, Bn to Qn;	5 V	123 ns + (0.55 ns/pF)C <sub>L</sub>	-	150	300	ns
	propagation delay	see <u>Figure 4</u>	10 V	49 ns + (0.23 ns/pF)C <sub>L</sub>	-	60	120	ns
			15 V	37 ns + (0.16 ns/pF)C <sub>L</sub>	-	45	90	ns
		In to Qn;	5 V	93 ns + (0.55 ns/pF)C <sub>L</sub>	-	120	240	ns
		see Figure 4	10 V	39 ns + (0.23 ns/pF)C <sub>L</sub>	-	50	100	ns
			15 V	27 ns + (0.16 ns/pF)C <sub>L</sub>	-	35	70	ns
t <sub>t</sub>	transition time	see Figure 4	5 V	10 ns + (1.00 ns/pF)C <sub>L</sub>	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C <sub>L</sub>	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C <sub>L</sub>	-	20	40	ns

<sup>[1]</sup> Qn is QA>B, QA<B or QA=B

Table 8. Dynamic power dissipation P<sub>D</sub>

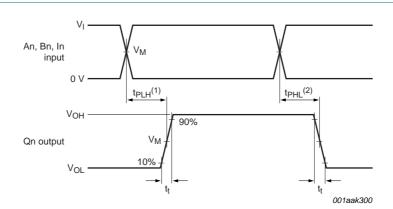
 $P_D$  can be calculated from the formulas shown.  $V_{SS} = 0$  V;  $C_L = 50$  pF;  $t_r = t_f \le 20$  ns;  $T_{amb} = 25$  °C.

Symbol	Parameter	$V_{DD}$	Typical formula for P <sub>D</sub> (μW)	where:
$P_D$	dynamic power dissipation	5 V	$P_D = 1250 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$f_i$ = input frequency in MHz,
		10 V	$P_D = 5500 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	fo = output frequency in MHz,
		15 V	$P_D = 15000 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$C_L$ = output load capacitance in pF,
				$V_{DD}$ = supply voltage in V,
				$\Sigma(f_o \times C_L)$ = sum of the outputs.

<sup>[2]</sup> In is IA>B, IA<B or IA=B

<sup>[3]</sup> The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown ( $C_L$  in pF).

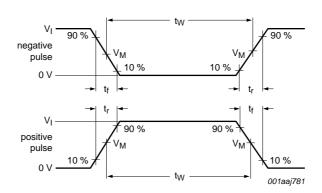
#### 11. Waveforms



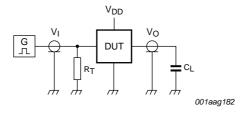
Measurement points shown in Table 9

- (1) Qn (QA>B, QA<B and QA=B) LOW to HIGH (t<sub>PLH</sub>) transitions triggered by An, Bn or IA<B, IA>B and IA=B as shown by <u>Table 3</u>.
- (2) Qn (QA>B, QA<B and QA=B) HIGH to LOW (tPHL) transitions triggered by An, Bn or IA<B, IA>B and IA=B as shown by Table 3.

Fig 4. Waveforms showing switching times



#### a. Input waveforms



#### b. Test circuit

Test data is given in Table 9.

Definitions for test circuit:

DUT = Device Under Test

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

Fig 5. Test circuit for measuring switching times

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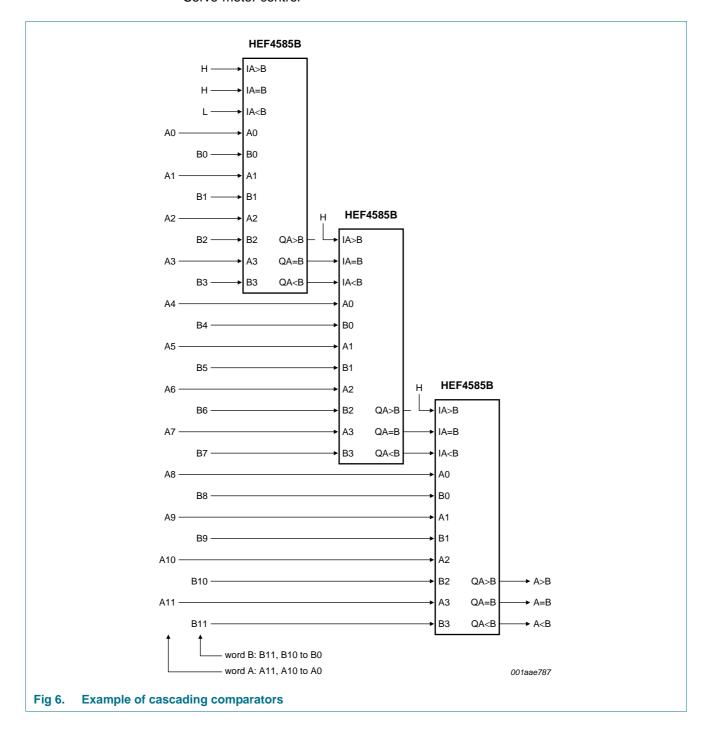
Table 9. Measurement points and test data

Supply voltage	Input	Load		
	VI	V <sub>M</sub>	t <sub>r</sub> , t <sub>f</sub>	CL
5 V to 15 V	$V_{DD}$	0.5V <sub>I</sub>	≤ 20 ns	50 pF

## 12. Application information

Some examples of applications for the HEF4585B are:

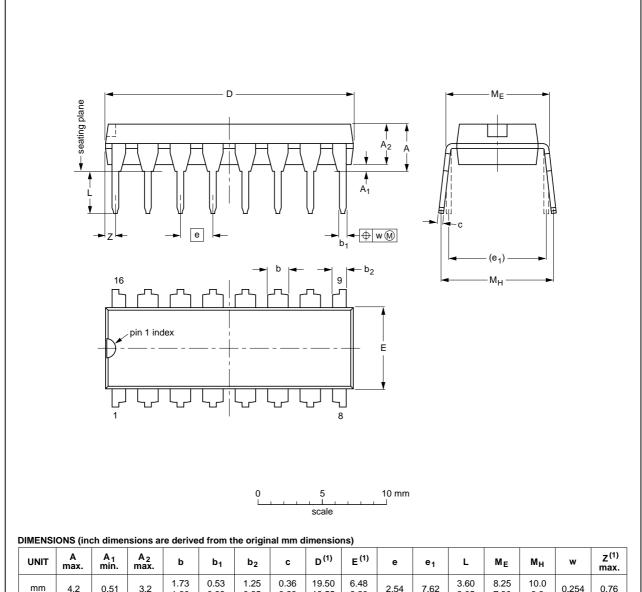
- Process controllers
- Servo-motor control



## 13. Package outline

#### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

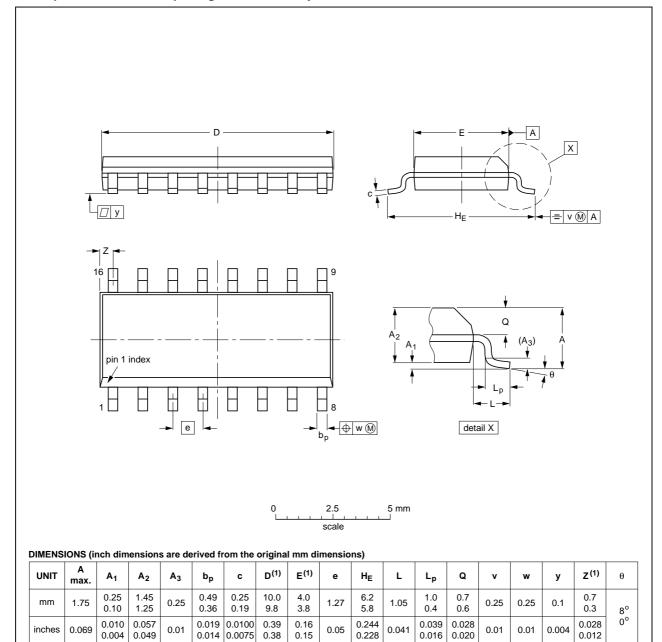
1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT38-4						<del>95-01-14</del> 03-02-13	

Package outline 38-4 (DIP16) Fig 7.

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



## Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE		
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

Fig 8. Package outline 109-1 (SO16)



## 14. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
HEF4585B v.6	20111121	Product data sheet	-	HEF4585B v.5	
Modifications:	<ul> <li>Section Applications removed</li> <li>Table 6: I<sub>OH</sub> minimum values changed to maximum</li> </ul>				
HEF4585B v.5	20091222	Product data sheet	-	HEF4585B v.4	
HEF4585B v.4	20090810	Product data sheet	-	HEF4585B_CNV v.3	
HEF4585B_CNV v.3	19950101	Product specification	-	HEF4585B_CNV v.2	
HEF4585B_CNV v.2	19950101	Product specification	-	-	

## 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## **HEF4585B**

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